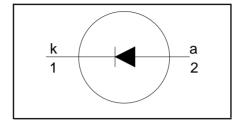
BY329 series

### **FEATURES**

- · Low forward volt drop
- Fast switching
- Soft recovery characteristic
- High thermal cycling performance
- Low thermal resistance

### **SYMBOL**



### **QUICK REFERENCE DATA**

$$V_{R} = 800 \text{ V/ } 1000 \text{ V/ } 1200 \text{ V}$$
 
$$I_{F(AV)} = 8 \text{ A}$$
 
$$I_{FSM} \leq 75 \text{ A}$$
 
$$t_{rr} \leq 135 \text{ ns}$$

### **GENERAL DESCRIPTION**

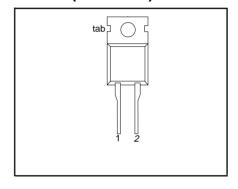
Glass-passivated double diffused rectifier diodes featuring low forward voltage drop, fast reverse recovery and soft recovery characteristic. The devices are intended for use in TV receivers, monitors and switched mode power supplies.

The BY329 series is supplied in the conventional leaded SOD59 (TO220AC) package.

### **PINNING**

PIN	DESCRIPTION	
1	cathode	
2	anode	
tab	cathode	

## SOD59 (TO220AC)



# **LIMITING VALUES**

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER CONDITIONS		MIN.	MAX.			UNIT
$V_{RSM}$	Peak non-repetitive reverse	BY329	-	<b>-800</b> 800	<b>-1000</b> 1000	<b>-1200</b> 1200	V
$oldsymbol{V_{RRM}}{oldsymbol{V_{RWM}}}$	voltage Peak repetitive reverse voltage Crest working reverse voltage		- -	800 600	1000 800	1200 1000	V V
I <sub>F(AV)</sub>	Average forward current <sup>1</sup>	square wave; $\delta$ = 0.5; $T_{mb} \le 122 ^{\circ}\text{C}$ sinusoidal; a = 1.57; $T_{mb} \le 125 ^{\circ}\text{C}$	-		8 7		A A
I <sub>F(RMS)</sub>	RMS forward current Repetitive peak forward current		- -		11 16		A A
I <sub>FSM</sub>	Non-repetitive peak forward current.	t = 10 ms t = 8.3 ms sinusoidal; T <sub>i</sub> = 150 °C prior to surge; with reapplied	- -		75 82		A A
$\begin{matrix} I^2t \\ T_{stg} \\ T_j \end{matrix}$	I <sup>2</sup> t for fusing Storage temperature Operating junction temperature	V <sub>RWM(max)</sub> t = 10 ms	- -40 -		28 150 150		A <sup>2</sup> s °C °C

<sup>1</sup> Neglecting switching and reverse current losses.

BY329 series

# THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
R <sub>th j-mb</sub>	Thermal resistance junction to mounting base		-	-	2.0	K/W
R <sub>th j-a</sub>		in free air.	-	60	-	K/W

# STATIC CHARACTERISTICS

T<sub>i</sub> = 25 °C unless otherwise stated

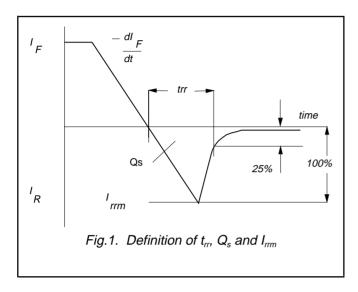
SY	MBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_R$		Forward voltage Reverse current	$I_F = 20 \text{ A}$ $V_R = V_{RWM}$ ; $T_j = 125 ^{\circ}\text{C}$		1.5 0.1	1.85 1.0	V mA

# **DYNAMIC CHARACTERISTICS**

T<sub>i</sub> = 25 °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
t <sub>rr</sub> Q <sub>s</sub> dl <sub>R</sub> /dt	Reverse recovery charge	$\begin{array}{l} I_F = 1 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 50 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } V_R \geq 30 \text{ V; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \\ I_F = 2 \text{ A; } -dI_F/dt = 20 \text{ A/}\mu\text{s} \end{array}$	- - -	100 0.5 50	135 0.7 60	ns μC A/μs

BY329 series



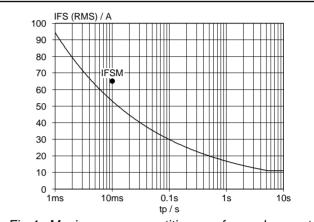


Fig.4. Maximum non-repetitive rms forward current.  $I_F = f(t_p)$ ; sinusoidal current waveform;  $T_j = 150^{\circ} C$  prior to surge with reapplied  $V_{RWM}$ .

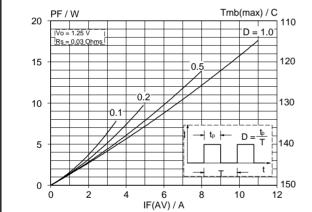


Fig.2. Maximum forward dissipation,  $P_F = f(I_{F(AV)})$ ; square wave current waveform; parameter D = duty  $cycle = t_p/T$ .

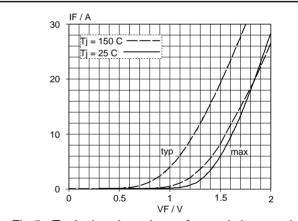
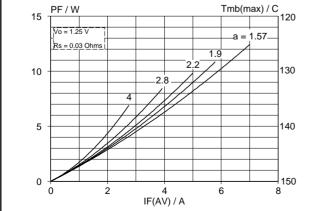
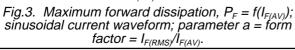
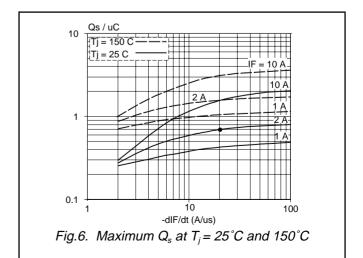


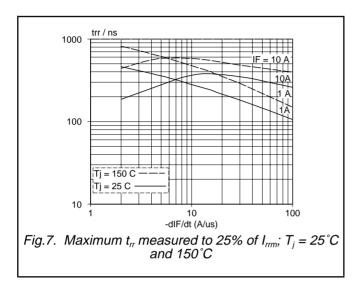
Fig.5. Typical and maximum forward characteristic;  $I_F = f(V_F)$ ; parameter  $T_j$ 

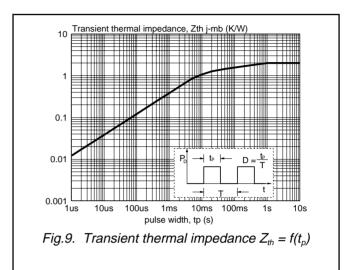






BY329 series





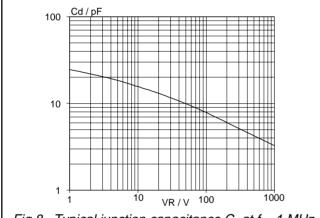
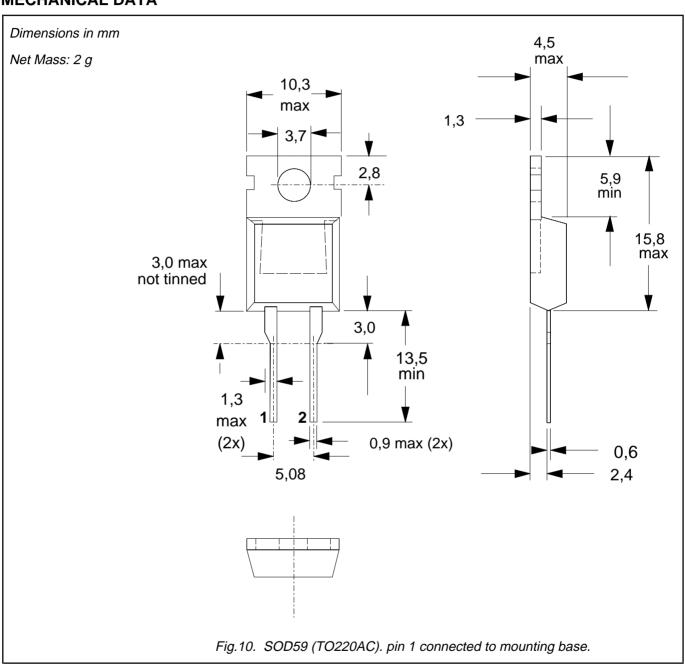


Fig.8. Typical junction capacitance  $C_d$  at f = 1 MHz,  $T_j = 25^{\circ}C$ 

BY329 series

### **MECHANICAL DATA**



- Refer to mounting instructions for TO220 envelopes.
   Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

# Rectifier diodes fast, soft-recovery

BY329 series

#### **DEFINITIONS**

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

#### **Application information**

Where application information is given, it is advisory and does not form part of the specification.

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